

Silicon PNP Power Transistors

2SB1404

DESCRIPTION

- With TO-220Fa package
- High DC current gain
- Low collector saturation voltage
- DARLINGTON

APPLICATIONS

- For use in low frequency power amplifier applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

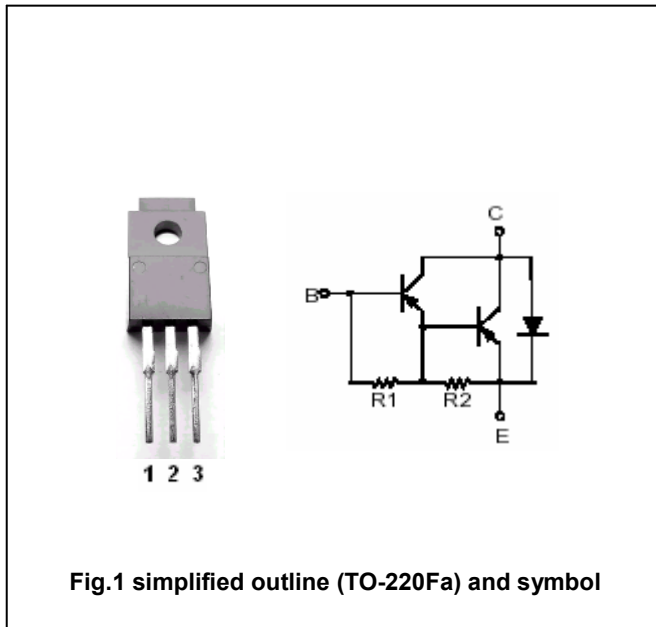


Fig.1 simplified outline (TO-220Fa) and symbol

Absolute maximum ratings(Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-base voltage	Open emitter	-120	V
V <sub>CEO</sub>	Collector -emitter voltage	Open base	-120	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	-7	V
I <sub>C</sub>	Collector current		-3	A
I <sub>CM</sub>	Collector current-peak		-6	A
P <sub>C</sub>	Collector power dissipation	T <sub>a</sub> =25°C	2	W
		T <sub>C</sub> =25°C	25	
T <sub>j</sub>	Junction temperature		150	°C
T <sub>stg</sub>	Storage temperature		-55~150	°C

## Silicon PNP Power Transistors

## 2SB1404

## CHARACTERISTICS

T<sub>j</sub>=25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =-25mA; R <sub>BE</sub> =∞	-120			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =-100μA; I <sub>E</sub> =0	-120			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =-50mA; I <sub>C</sub> =0	-7			V
V <sub>CEsat-1</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =-1.5A ; I <sub>B</sub> =-3mA			-1.5	V
V <sub>CEsat-2</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =-3A ; I <sub>B</sub> =-30mA			-3.0	V
V <sub>BEsat-1</sub>	Base-emitter saturation voltage	I <sub>C</sub> =-1.5A ; I <sub>B</sub> =-3mA			-2.0	V
V <sub>BEsat-2</sub>	Base-emitter saturation voltage	I <sub>C</sub> =-3A ; I <sub>B</sub> =-30mA			-3.5	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =-100V; I <sub>E</sub> =0			-10	μA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> =-100V; R <sub>BE</sub> =∞			-10	μA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =-1.5A ; V <sub>CE</sub> =-3V	1000		20000	

Silicon PNP Power Transistors

2SB1404

PACKAGE OUTLINE

